Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-245-5477

	closure Material:
Gla	ass
Ov	erall Length:
0.2	200 inches
Те	rminal Length:
0.5	i00 inches
Ov	erall Diameter:
0.0	990 inches
Jo	int Electronic Device Engineering Council/jedec/case Outline Designation:
Do	-35
Мс	ounting Method:
Те	rminal
Fe	atures Provided:
He	rmetically sealed case
Se	miconductor Material:
Sil	icon
Vo	Itage Rating In Volts Per Characteristic:
6.2	2 regulator voltage
Vo	Itage Tolerance In Percent:
-5.	0/+5.0
Cu	rrent Rating Per Characteristic:
5.0	0 milliamperes source cutoff current horsepower metric
Ро	wer Rating Per Characteristic:
0.4	0 watts small-signal input power, common-collector preset
Ма	iximum Operating Tempurature Per Measurement Point:
17	5.0 degrees celsius junction
Те	rminal Type And Quantity:
2ι	ininsulated wire lead
Sh	elf Life:
N/a	a
Un	it Of Measure:
De	militarization:
No	
Fii	g:
	10a0